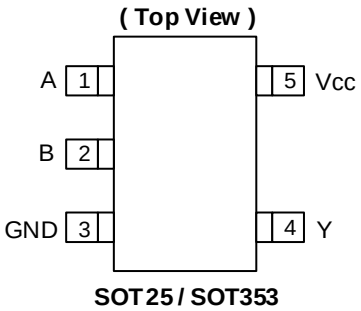
Description

The 74AHCT1G00Q is an automotive compliant single, two-input positive NAND gate with a standard push-pull output. The device is designed for operation with a power supply range of 4.5V to 5.5V. The gate performs the positive Boolean function:

$$Y = \overline{A \bullet B} \quad \text{or} \quad Y = \overline{A} + \overline{B}$$

Pin Assignments



SOT25 / SOT353

Features

- Grade 1 Ambient Temperature Operation: -40°C to +125°C
- Supply Voltage Range from 4.5V to 5.5V
- ±8mA Output Drive at 5.0V
- CMOS Low-Power Consumption
- High Noise Immunity
- Inputs Not Limited by V_{CC}
- Balanced Propagation Delays
- Balanced Drive Capability
- ESD Protection Tested per AEC-Q100
- Exceeds 2000V Human Body Model (AEC-Q100-002)
- Exceeds 1000V Charged Device Model (AEC-Q100-011)
- Latch-Up Exceeds 100mA (AEC-Q100-004)
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The 74AHCT1G00Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**
  https://www.diodes.com/quality/product-definitions/

Applications

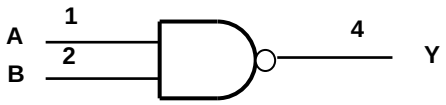
- General purpose logics
- Wide array of products, such as:
  - Automotive applications within grade 1 temperature range
  - Industrial computing/controls/automations
  - High reliability networking/communications
  - Industrial/Agricultural equipment

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Descriptions

Pin Name	Description
A	Data Input
B	Data Input
GND	Ground
Y	Data Output
V_{CC}	Supply Voltage

Logic Diagram



Function Table

Inputs		Output
A	**B**	**Y**
H	H	L
L	X	H
X	L	H

Absolute Maximum Ratings (Notes 4 & 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
V_{CC}	Supply Voltage Range	-0.5 to 6.5	V
V_I	Input Voltage Range	-0.5 to 6.5	V
V_O	Voltage Applied to Output in High or Low State	-0.5 to V_{CC} + 0.5	V
I_{IK}	Input Clamp Current $V_I < 0$	-20	mA
I_{OK}	Output Clamp Current ($V_O < 0$ or $V_O > V_{CC}$)	±20	mA
I_O	Continuous Output Current (V_O = 0 to V_{CC})	±25	mA
I_{CC}	Continuous Current Through V_{CC}	75	mA
I_{GND}	Continuous Current Through GND	-75	mA
T_J	Operating Junction Temperature	-40 to +150	°C
T_{STG}	Storage Temperature	-65 to +150	°C
P_D	Total Power Dissipation (Note 6)	250	mW

Notes:
4. Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
5. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.
6. This will need to be derated at higher operating temperatures to prevent exceeding maximum T_J. Refer to package thermal characteristics section.

Recommended Operating Conditions (Note 7)

Symbol	Parameter		Min	Max	Unit
V_{CC}	Operating Voltage	—	4.5	5.5	V
V_{IH}	High-Level Input Voltage	V_{CC} = 5V ± 0.5V	2.0	—	V
V_{IL}	Low-Level Input Voltage	V_{CC} = 5V ± 0.5V	—	0.8	V
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage		0	V_{CC}	V
I_{OH}	High-Level Output Current	V_{CC} = 5V ± 0.5V	—	-8	mA
I_{OL}	Low-Level Output Current	V_{CC} = 5V ± 0.5V	—	8	mA
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate	V_{CC} = 5V ± 0.5V	—	20	ns/V
T_A	Ambient Temperature	—	-40	+125	°C

Note: 7. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (All typical values are at V_{CC} = 5V, T_A = +25°C.)

Symbol	Parameter	Test Conditions	Vcc	+25°C			-40°C to +85°C		-40°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
V_{OH}	High Level Output Voltage	V_I = V_{IH} or V_{IL} I_{OH} = -50μA	4.5V	4.4	4.5	—	4.4	—	4.4	—	V
		V_I = V_{IH} or V_{IL} I_{OH} = -8mA	4.5V	3.94	—	—	3.8	—	3.70	—	V
V_{OL}	Low Level Output Voltage	V_I = V_{IH} or V_{IL} I_{OL} = 50μA	4.5V	—	0	0.1	—	0.1	—	0.1	V
		V_I = V_{IH} or V_{IL} I_{OL} = 8mA	4.5V	—	—	0.36	—	0.44	—	0.55	V
I_I	Input Current	V_I = 5.5V or GND	0V to 5.5V	—	—	±0.1	—	±1	—	±2	μA
ΔI_{CC}	Additional Supply Current	Per input pin, V_I = 3.4V, Other inputs at V_{CC} or GND, I_O = 0	5.5V	—	—	1.35	—	1.5	—	1.5	mA
I_{CC}	Supply Current	V_I = 5.5V or GND I_O = 0	5.5V	—	—	1	—	10	—	40	μA
C_I	Input Capacitance	V_I = V_{CC} or GND	5.5V	—	1.5	10	—	10	—	10	pF

Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Typ	Max	Unit
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOT25	Note 8	—	184	—	°C/W
		SOT353		—	385	—	
θ_{JC}	Thermal Resistance Junction-to-Case	SOT25	Note 8	—	62	—	°C/W
		SOT353		—	164	—	

Note: 8. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

V_{CC} = 5V ± 0.5V (See Figure 1, Typical Values at V_{CC} = 5V.)

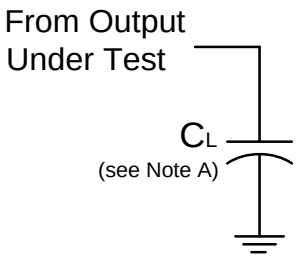
Parameter	From (Input)	To (Output)	Test Conditions	+25°C			-40°C to +85°C		-40°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t_{PD}	A or B	Y	C_L = 15pF	1.0	3.6	6.2	1.0	7.1	1.0	8.0	ns
			C_L = 50pF	1.0	5.0	7.9	1.0	9.0	1.0	10.0	ns

Operating Characteristics

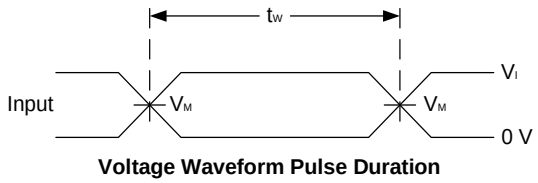
T_A = +25°C

Parameter		Test Conditions	V_{CC} = 5V Typ	Unit
C_{PD}	Power Dissipation Capacitance	f = 1MHz No Load	10	pF

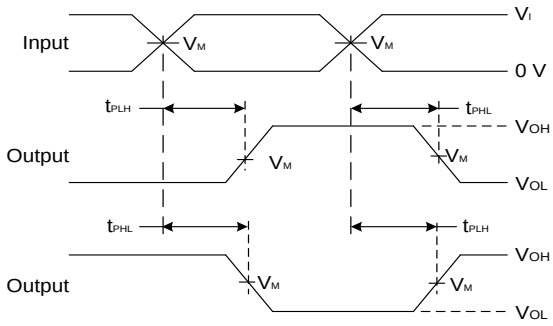
Measurement Information



V_{CC}	Inputs			Output	C_L
	V_I	t_R/t_F	V_M	V_M	
5V±0.5V	GND to V_{CC}	≤3ns	1.5V	$V_{CC}/2$	15pF
5V±0.5V	GND to V_{CC}	≤3ns	1.5V	$V_{CC}/2$	50pF



Voltage Waveform Pulse Duration

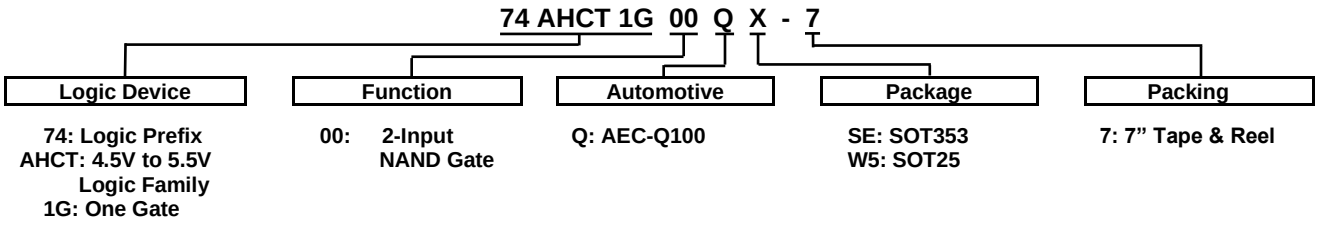


Voltage Waveform Propagation Delay Times
Inverting and Non-Inverting Outputs

Figure 1. Load Circuit and Voltage Waveforms

Notes:
A. Includes test lead and test apparatus capacitance.
B. All pulses are supplied at pulse repetition rate ≤ 1MHz.
C. Inputs are measured separately one transition per measurement.
D. t_{PLH} and t_{PHL} are the same as t_{PD}.

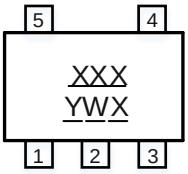
Ordering Information (Note 9)



Part Number	Package Code	Package (Notes 10 & 11)	Package Size	Packing	
				Qty.	Carrier
74AHCT1G00QSE-7	SE	SOT353	2.15mm × 2.1mm × 1.1mm 0.65mm Lead Pitch	3000	7" Tape and Reel
74AHCT1G00QW5-7	W5	SOT25	3.0mm × 2.8mm × 1.2mm 0.95mm Lead Pitch	3000	7" Tape and Reel

Notes: 9. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.
10. Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html.
11. The taping orientation is located on our website at https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.

Marking Information



SOT25 / SOT353

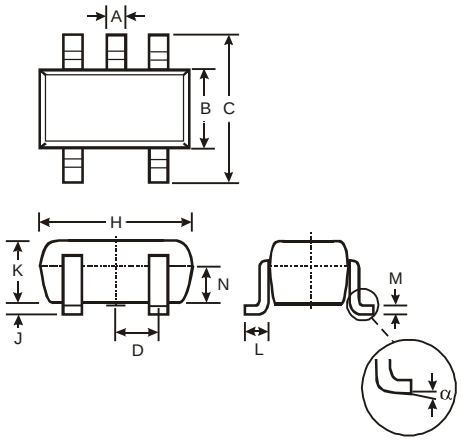
XXX: Identification Code
Y : Year 0 to 9
W: Week: A to Z 1 to 26 Week
a to z 27 to 52 Week
z Represents Week 52 and 53
X: A to Z: Internal Code

Part Number	Package	Identification Code
74AHCT1G00QW5-7	SOT25	ZRQ
74AHCT1G00QSE-7	SOT353	ZRQ

Package Outline Dimensions

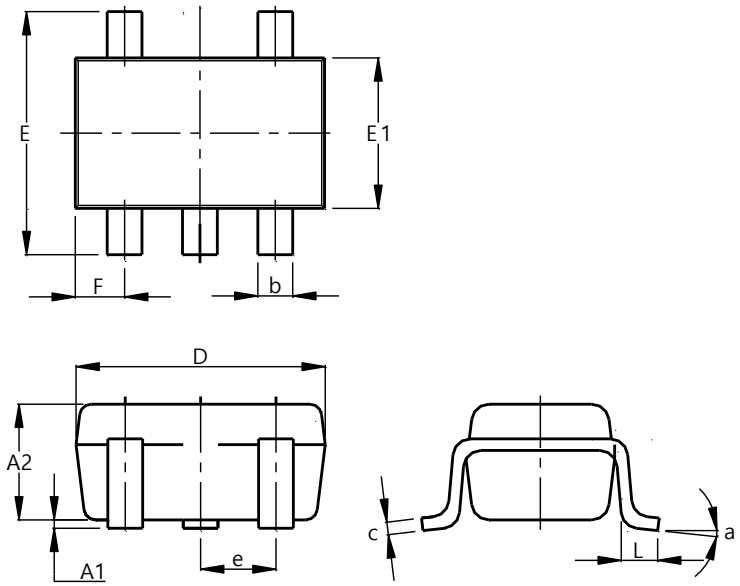
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



SOT25			
Dim	**Min**	**Max**	**Typ**
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	-	-	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	-
All Dimensions in mm			

(2) Package Type: SOT353

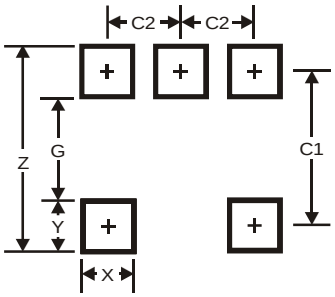


SOT353			
Dim	**Min**	**Max**	**Typ**
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.10	0.30	0.25
c	0.10	0.22	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
F	0.40	0.45	0.425
L	0.25	0.40	0.30
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

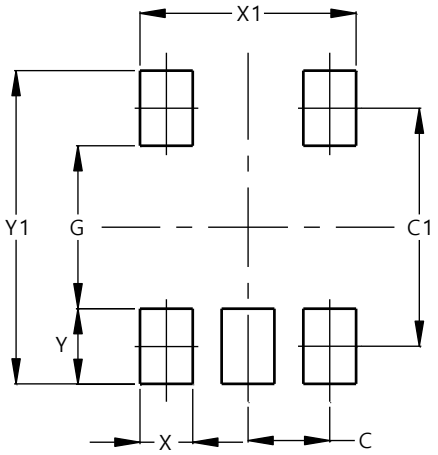
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



Dimensions	Value
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

(2) Package Type: SOT353



Dimensions	Value (in mm)
C	0.650
C1	1.900
G	1.300
X	0.420
X1	1.720
Y	0.600
Y1	2.500

Mechanical Data

SOT25

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.0158 grams (Approximate)

SOT353

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.0064 grams (Approximate)

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